NSN 5961-01-215-5985

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-215-5985 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **End Application:** 1430-01-215-7255 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 collector to base voltage/static/emitter open and 350.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 660.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 18876-11439612 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-215-5985 Transistor - Page 2 of 2



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